NSN 5962-01-410-8741

Memory Microcircuit - Page 1 of 1

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Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-55.0/+125.0 degrees celsius

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

50.00 milliamperes peak forward surge current horsepower metric

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads

Time Rating Per Chacteristic:

50.00 nanoseconds access

Memory Device Type:

First-in first-out

Hybrid Technology Type:

Monolithic

Terminal Type And Quantity:

40 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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